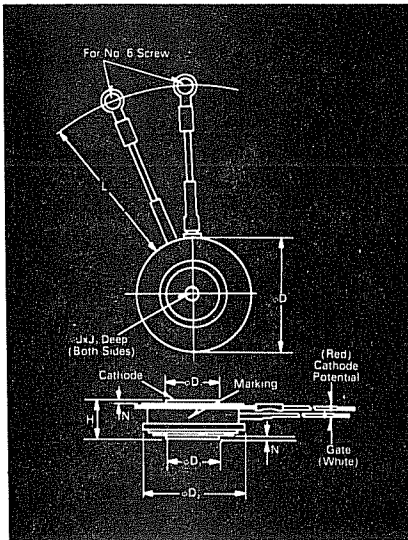




# Fast Switching SCR T627\_15

**150A Avg.  
(235 RMS)  
Up to 1200 Volts  
10-50  $\mu$ s**



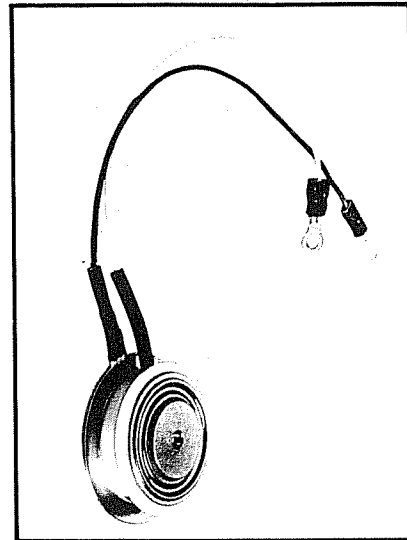
T62 Outline

**Features:**

- Center fired di/namic gate
- High di/dt with soft gate control
- High frequency operation
- Sinusoidal waveform operation to 20 KHz
- Rectangular waveform operation to 20 KHz
- Low dynamic forward voltage drop
- Low switching losses at high frequency

Symbol	Inches		Millimeters	
	Min.	Max.	Min.	Max.
$\phi D$	1.610	1.650	40.89	41.91
$\phi D_1$	.745	.755	18.92	19.18
$\phi D_2$	1.420	1.460	36.07	37.08
H	.500	.560	12.70	14.22
$\phi J$	.135	.145	3.43	3.68
$J_1$	.072	.082	1.83	2.08
L	7.75	8.50	196.85	215.90
N	.030	.076		

Creep Distance—.34 in. min. (8.64 mm).  
Strike Distance—.26 in. min. (6.60 mm).  
(In accordance with NEMA standards.)  
Finish—Nickel Plate.  
Approx. Weight—2.3 oz. (66 g).  
1. Dimension "H" is clamped dimension.



**Applications:**

- Inverters for  
Ups  
Induction Heating  
Motor Control
- Choppers
- Crowbars

**Ordering Information**

Type	Voltage		Current		Turn-off		Gate Current		Leads		
	Code	$V_{DRM}$ and $V_{RRM}$ (V)	$I_T(av)$ (A)	Code	$t_q$ $\mu$ sec	Code	$I_{GT}$ (ma)	Code	Case	Code	
T627	01	100	150	15	10	8	150	4	T62	DN	
	02	200			15						7
	03	300			20						6
	04	400			30						5
	05	500			40						4
	06	600			50						3
	07	700									
	08	800									
	09	900									
	10	1000									
	11	1100									
	*12	1200									

**Example**

Obtain optimum device performance for your application by selecting proper Order Code.

Type T627 rated at 150A average with  $V_{DRM} = 1000V$ ,  $I_{GT} = 150$  ma,  $t_q = 20 \mu$ sec max. and flex leads—order as:

Type	Voltage	Current	Turn Off	Gate Current	Leads
T 6 2 7	1 0	1 5	6	4	D N

\*for 10  $\mu$ sec turn-off, consult factory

Westinghouse Electric Corporation • Semiconductor Division • Youngwood, Pa. 15697

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**Voltage**

Blocking State Maximums  $\textcircled{1}$  ( $T_J = 125^\circ\text{C}$ )

Symbol	100	200	300	400	500	600	700	800	900	1000	1100	1200
Repetitive peak forward blocking voltage, V ... $V_{DRM}$	100	200	300	400	500	600	700	800	900	1000	1100	1200
Repetitive peak reverse voltage, V ... $V_{RRM}$	100	200	300	400	500	600	700	800	900	1000	1100	1200
Non-repetitive transient peak reverse voltage, $t \leq 5.0$ msec, V ... $V_{RSM}$	200	300	400	500	600	700	800	900	1000	1100	1200	1300
Forward leakage current, mA peak ... $I_{DRM}$	←----- 25 -----→											
Reverse leakage current, mA peak ... $I_{RRM}$	←----- 25 -----→											

**Current**

Conducting State Maximums ( $T_J = 125^\circ\text{C}$ )

Symbol	T627__15
RMS forward current, A ... $I_T(\text{rms})$	235
Ave. forward current, A ... $I_T(\text{av})$	150
One-half cycle surge current $\textcircled{2}$ , A ... $I_{TSM}$	3500
$I^2t$ for fusing (for times $\geq 8.3$ ms) $A^2 \text{ sec.}$ ... $I^2t$	50,000
Forward voltage drop at $I_{TM} = 625A$ and $T_J = 25^\circ\text{C}$ , V ... $V_{TM}$	2.35
Min. repetitive $di/dt$ $\textcircled{3}$ , $A/\mu\text{sec}$ $\textcircled{4}$ $\textcircled{5}$ ... $di/dt$	200

**Switching**

( $T_J = 25^\circ\text{C}$ )

Symbol	
Max. turn-off time, $I_T = 150A$ , $T_J = 125^\circ\text{C}$ , $di/dt = 12.5 \textcircled{6}$ $A/\mu\text{sec}$ , reappplied $dv/dt = 20V/\mu\text{sec}$ $\textcircled{7}$ , linear to $0.8 V_{DRM}$ , $\mu\text{sec.}$ ... $t_q$	10 to 50
Typ. turn-on-time, $I_T = 100A$ , $V_D = 100V$ $\textcircled{8}$ , $\mu\text{sec.}$ ... $t_{on}$	3.5
Min. critical $dv/dt$ , exponential to $V_{DRM}$ , $T_J = 125^\circ\text{C}$ , $V/\mu\text{sec}$ $\textcircled{9}$ ... $dv/dt$	300
Min. $di/dt$ $A/\mu\text{sec}$ $\textcircled{10}$ $\textcircled{11}$ ... $di/dt$	800

**Gate**

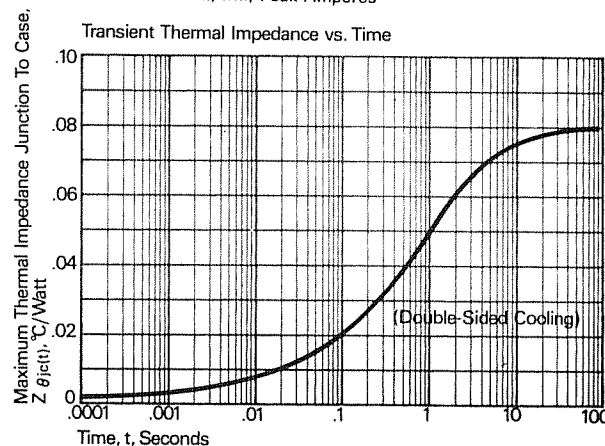
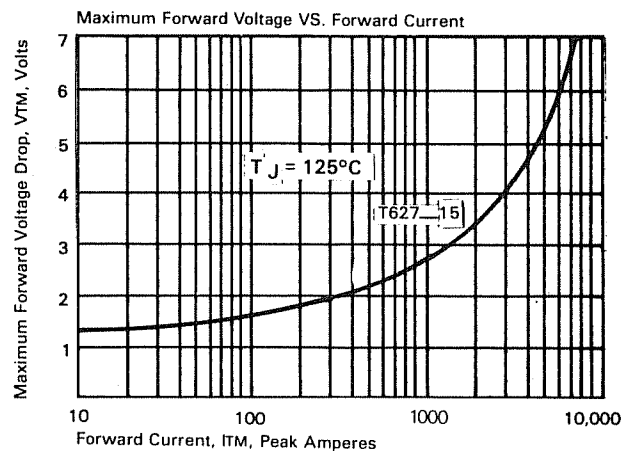
Maximum Parameters ( $T_J = 25^\circ\text{C}$ )

Symbol	
Gate current to trigger at $V_D = 12V$ , mA ... $I_{GT}$	150
Gate voltage to trigger at $V_D = 12V$ , V ... $V_{GT}$	3
Non-triggering gate voltage, $T_J = 125^\circ\text{C}$ , and rated $V_{DRM}$ , V ... $V_{GDM}$	0.15
Peak forward gate current, A ... $I_{GTM}$	4
Peak reverse gate voltage, V ... $V_{GRM}$	5
Peak gate power, Watts ... $P_{GM}$	16
Average gate power, Watts ... $P_{G(av)}$	3

**Thermal and Mechanical**

Symbol	
Min., Max. oper. junction temp., $^\circ\text{C}$ ... $T_J$	-40 to +125
Min., Max. storage temp., $^\circ\text{C}$ ... $T_{stg}$	-40 to +150
Min., Max. Mounting Force, lb. $\textcircled{12}$ ...	1000 to 1400
Max. thermal resistance, Double side cooled	
Junction to case, $^\circ\text{C}/\text{Watt}$ ... $R_{\theta JC}$	.08
Case to sink, lubricated, $^\circ\text{C}/\text{Watt}$ ... $R_{\theta CS}$	.02

- $\textcircled{1}$  Consult recommended mounting procedures.
- $\textcircled{2}$  Applies for zero or negative gate bias.
- $\textcircled{3}$  Per JEDEC RS-397, 5.2.2.1.
- $\textcircled{4}$  With recommended gate drive.
- $\textcircled{5}$  Higher  $dv/dt$  ratings available, consult factory.
- $\textcircled{6}$  Per JEDEC standard RS-397, 5.2.2.6.
- $\textcircled{7}$  For operation with antiparallel diode, consult factory.



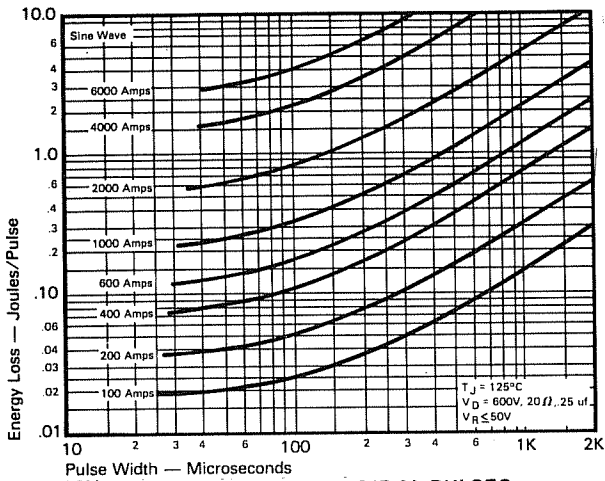
FAST SWITCHING THYRISTORS



# Fast Switching SCR T627\_15

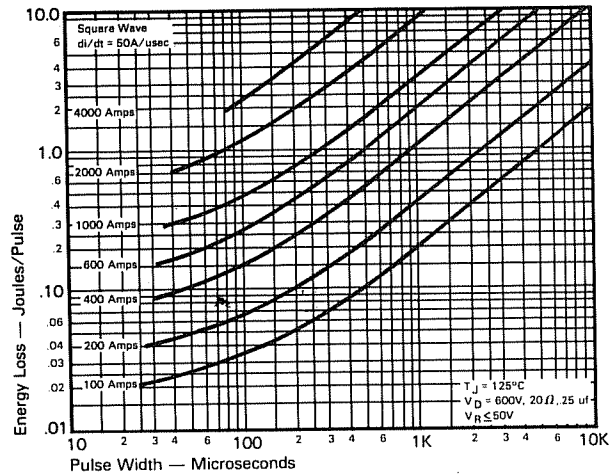
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## Sinusoidal Current Data

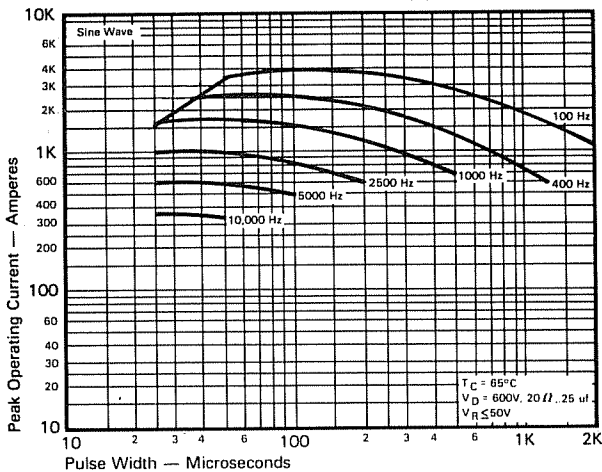


ENERGY PER PULSE FOR SINUSOIDAL PULSES

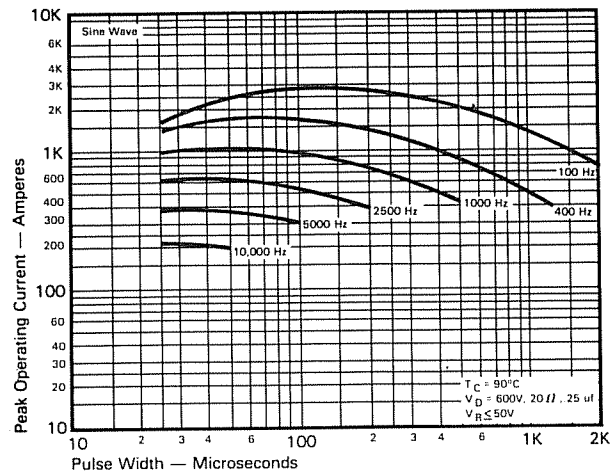
## Trapezoidal Wave Current Data



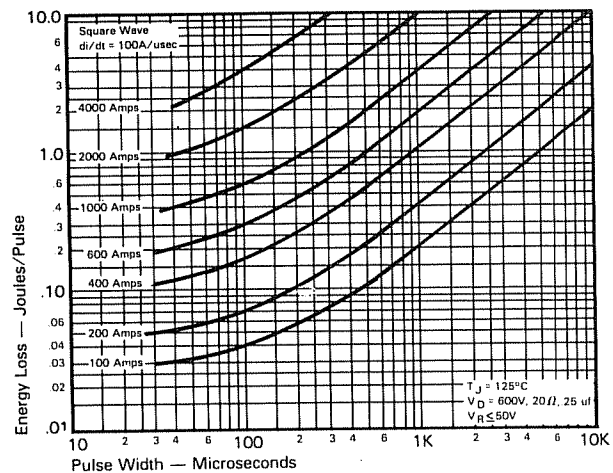
ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 50A/usec)



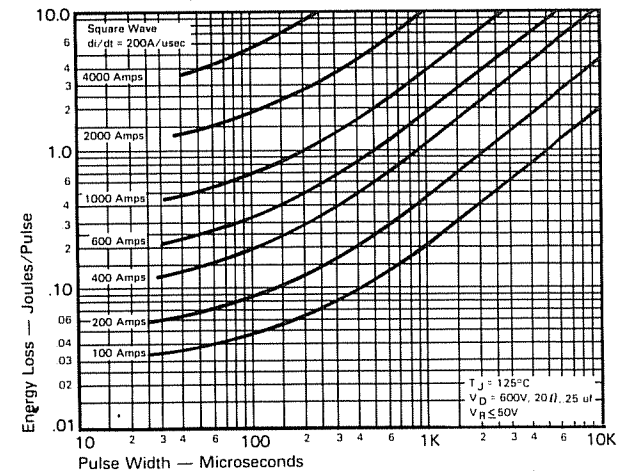
MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT  
vs. PULSE WIDTH ( $T_C = 65^\circ\text{C}$ )



MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT  
vs. PULSE WIDTH ( $T_C = 90^\circ\text{C}$ )



ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 100A/usec)



ENERGY PER PULSE FOR TRAPEZOIDAL PULSES  
(di/dt = 200A/usec)

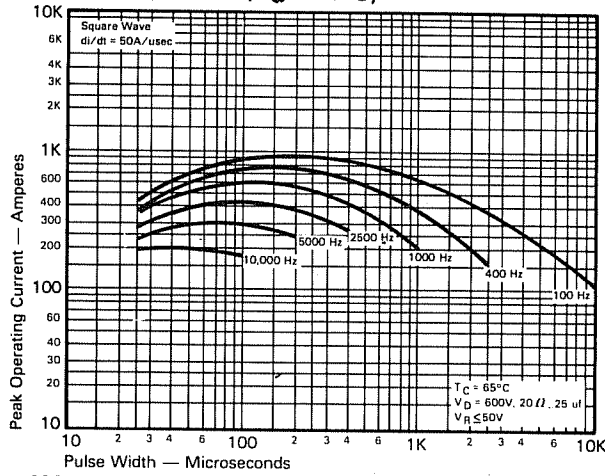
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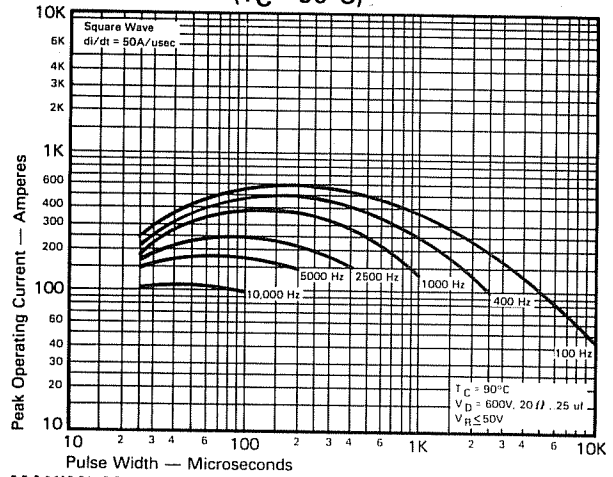


**Trapezoidal Wave Current Data**  
( $T_C = 65^\circ\text{C}$ )

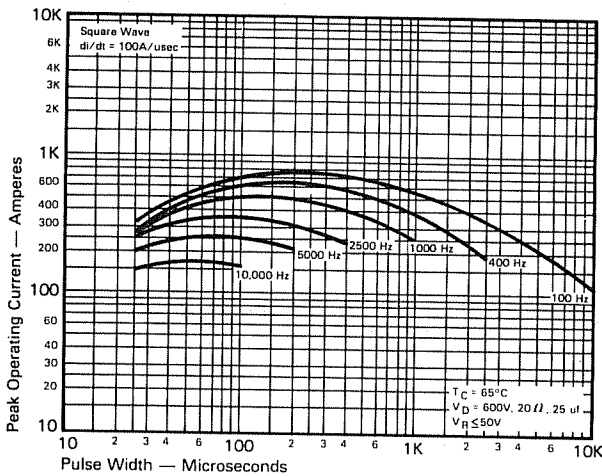


**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 50A/usec$ )**

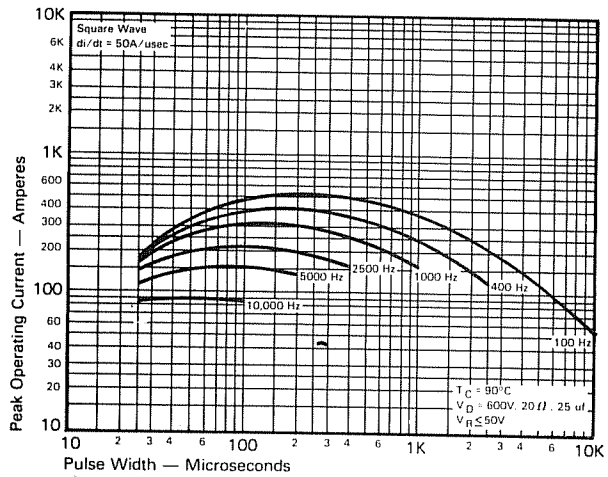
**Trapezoidal Wave Current Data**  
( $T_C = 90^\circ\text{C}$ )



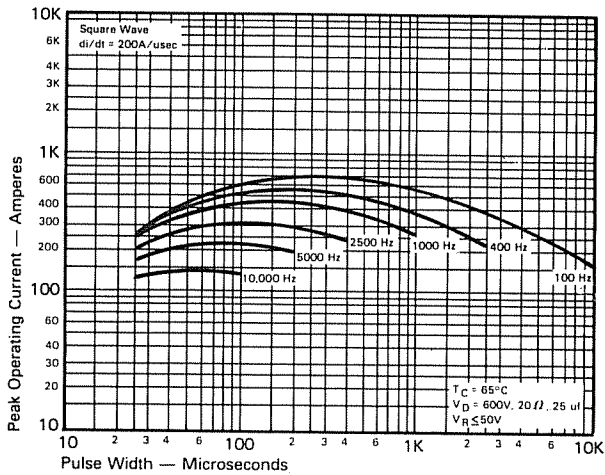
**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 50A/usec$ )**



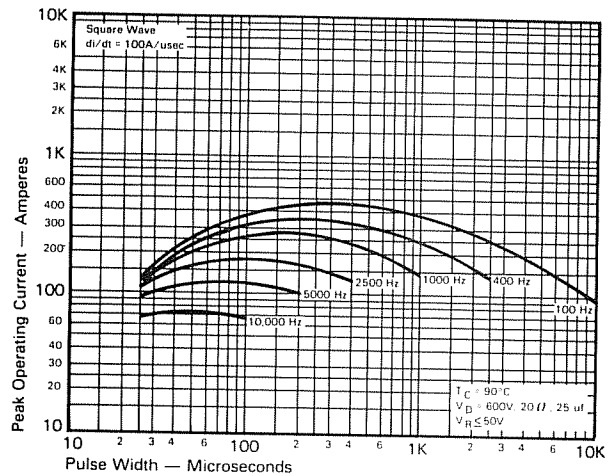
**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 100A/usec$ )**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 100A/usec$ )**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 200A/usec$ )**



**MAXIMUM ALLOWABLE PEAK ON-STATE CURRENT vs. PULSE WIDTH ( $di/dt = 200A/usec$ )**

FAST SWITCHING THYRISTORS